



Product Summary

Device	V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C				
		1.5Ω @ V _{GS} = 4.5V	0.22A				
Q1	30V	2.0Ω @ V _{GS} = 2.5V					
QI	300	3.0Ω @ V _{GS} = 1.8V					
		4.5Ω @ V _{GS} = 1.5V					
		5Ω @ V _{GS} = -4.5V					
Q2	-30V	6Ω @ V _{GS} = -2.5V	-0 2A				
QZ	-30 V	7Ω @ V _{GS} = -1.8V	-0.2A				
		10Ω @ V _{GS} = -1.5V					

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch





Top View

Features and Benefits

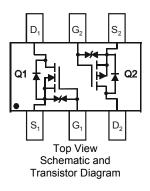
- Low On-Resistance
- Very low Gate Threshold Voltage, 1.0V max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package 1mm x 1mm
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

COMPLEMENTARY PAIR ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SOT963
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 (c3)
- Weight: 0.027 grams (approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMC31D5UDJ-7	SOT963	10K/Tape & Reel
DMC31D5UDJ-7B	SOT963	10K/Tape & Reel

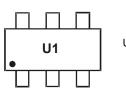
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html. The options -7 and -7B stand for different taping orientations.

Marking Information

Notes:



U1 = Product Type Marking Code

^{2.} See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.



Maximum Ratings Q1 N-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units	
Drain-Source Voltage	V _{DSS}	30	V			
Gate-Source Voltage	V _{GSS}	±12	V			
$(Continuous Drain (Current (Note 5)) V_{oo} = 4.5V$		T _A = +25°C T _A = +70°C	Ι _D	220 160	mA	
Maximum Continuous Body Diode Forward Currer	ls	200	mA			
Pulsed Drain Current (Note 6)	I _{DM}	600	mA			

Maximum Ratings Q2 P-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-30	V		
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 5) $V_{00} = -4.5V$		T _A = +25°C T _A = +70°C	ID	-200 -140	mA
Maximum Continuous Body Diode Forward Curren	ls	-200	mA		
Pulsed Drain Current (Note 6)	I _{DM}	-600	mA		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		PD	350	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	361	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	C°

Electrical Characteristics Q1 N-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIII	Тур	WIAX	Unit	Test condition
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	i	V	V _{GS} = 0V, I _D = 250µA
,,				100	nA	
Zero Gate Voltage Drain Current $@T_C = +25^{\circ}C$		_	_			$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±10	μA	V_{GS} = ±10V, V_{DS} = 0V
ON CHARACTERISTICS (Note 7)				i	i	İ
Gate Threshold Voltage	V _{GS(th)}	0.4	—	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
		—	0.9	1.5		V_{GS} = 4.5V, I_{D} = 100mA
		_	1.0	2.0		V_{GS} = 2.5V, I_{D} = 50mA
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.2	3.0	Ω	V _{GS} = 1.8V, I _D = 20mA
		_	1.4	4.5		V _{GS} = 1.5V, I _D = 10mA
		_	2.3			V _{GS} = 1.2V, I _D = 1mA
Diode Forward Voltage	V _{SD}		0.6	1.0	V	V _{GS} = 0V, I _S = 10mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	22.6		pF	
Output Capacitance	Coss	_	2.68		pF	−V _{DS} = 15V, V _{GS} = 0V, −f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	1.8		pF	
Total Gate Charge	Qg	_	0.38	_	nC	
Gate-Source Charge	Q _{gs}	_	0.05	—	nC	−V _{GS} = 4.5V, V _{DS} = 15V, −I _D = 200mA
Gate-Drain Charge	Q _{gd}	_	0.07		nC	-1D = 20011A
Turn-On Delay Time	t _{D(on)}	_	3.2		ns	
Turn-On Rise Time	tr	_	2.2	—	ns	V _{DD} = 15V, V _{GS} = 4.5V,
Turn-Off Delay Time	t _{D(off)}	_	21		ns	$R_{G} = 2\Omega, I_{D} = 200 \text{mA}$
Turn-Off Fall Time	t _f	_	7.5		ns	



Electrical Characteristics Q2 P-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						·	
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—		V	V_{GS} = 0V, I_{D} = -250 μ A	
Zero Gate Voltage Drain Current @T _C = +25°C	IDSS	_	—	100	nA	V _{DS} = -24V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	—	±10	μA	V_{GS} = ±10V, V_{DS} = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-0.4	—	-1.0	V	V_{DS} = V_{GS} , I_D = -250 μ A	
		_	2.0	5	Ω	V _{GS} = -4.5V, I _D = -100mA	
		—	2.5	6		V_{GS} = -2.5V, I_D = -50mA	
Static Drain-Source On-Resistance	R _{DS(ON)}	—	3.0	7		V _{GS} = -1.8V, I _D = -20mA	
		_	3.4	10		V _{GS} = -1.5V, I _D = -10mA	
		_	5.1	_		V _{GS} = -1.2V, I _D = -1mA	
Diode Forward Voltage	V _{SD}	_	-0.6	-1.0	V	V _{GS} = 0V, I _S = -10mA	
DYNAMIC CHARACTERISTICS (Note 8)				•		•	
Input Capacitance	Ciss	_	21.8		pF		
Output Capacitance	Coss	_	2.82		pF	V _{DS} = -15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	1.66	_	pF	1 - 1.000112	
Total Gate Charge	Qg	_	0.35		nC		
Gate-Source Charge	Q _{gs}		0.05	_	nC	$V_{GS} = -4.5V, V_{DS} = -15V,$	
Gate-Drain Charge	Q _{gd}	_	0.10		nC	– I _D = -200mA	
Turn-On Delay Time	t _{D(on)}	—	3.5		ns		
Turn-On Rise Time	tr	—	5.2		ns	V _{DD} = -15V, V _{GS} = -4.5V,	
Turn-Off Delay Time	t _{D(off)}	_	18.8		ns	$R_{G} = 2\Omega, I_{D} = -200 \text{mA}$	
Turn-Off Fall Time	t _f	_	8.7		ns	7	

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

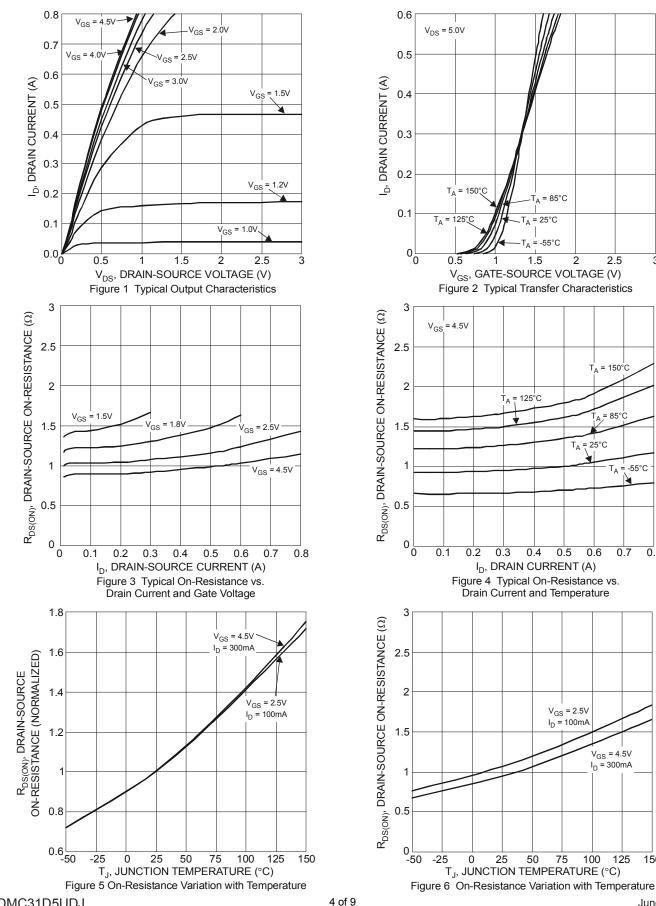
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



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N-CHANNEL



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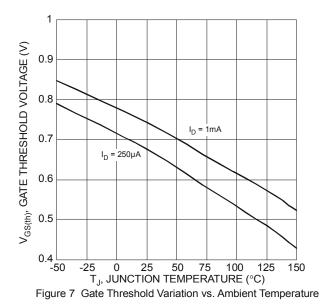
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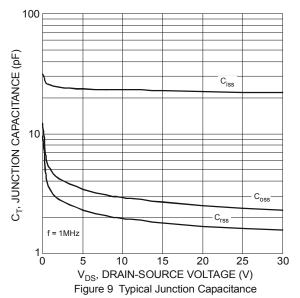
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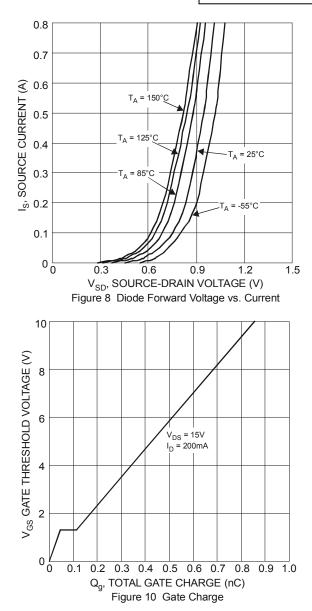
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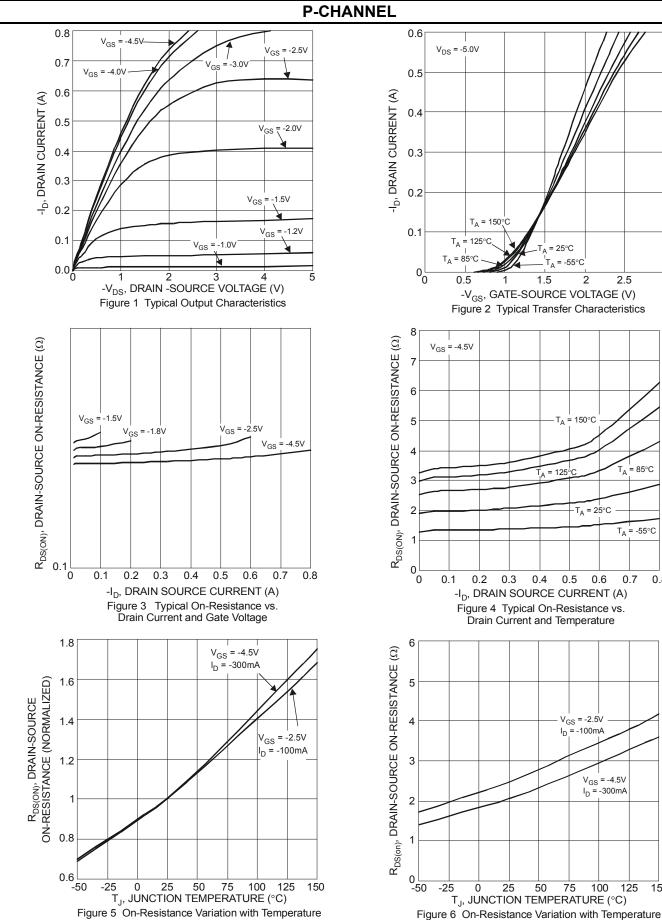


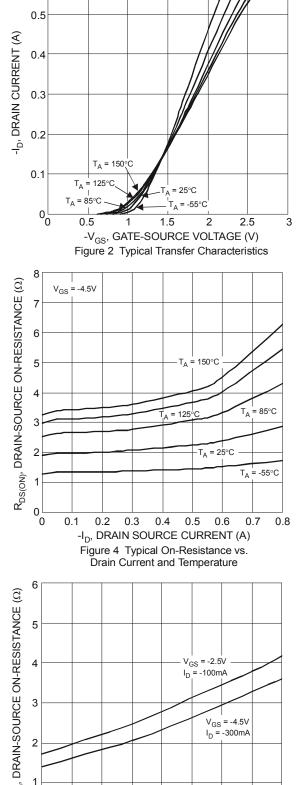


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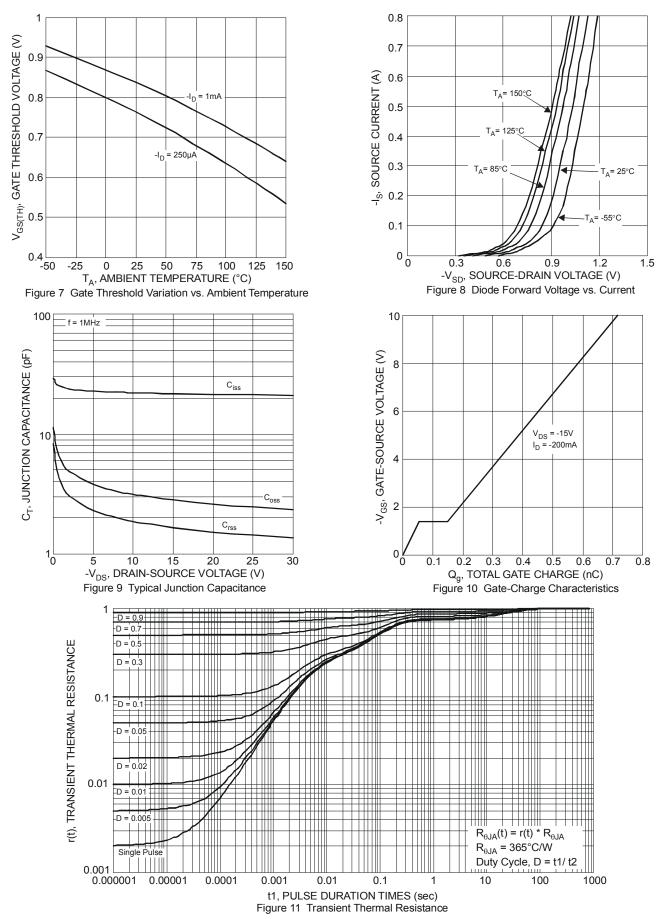
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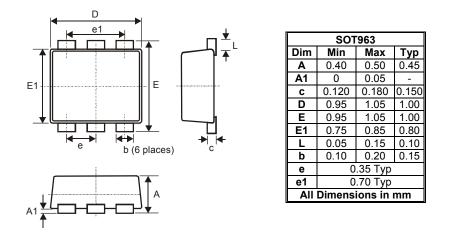
NEW PRODUCT

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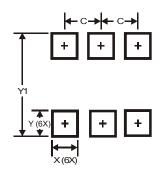
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.350
Х	0.200
Y	0.200
Y1	1.100



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